

TOSHIBA THYRISTOR SILICON PLANAR TYPE

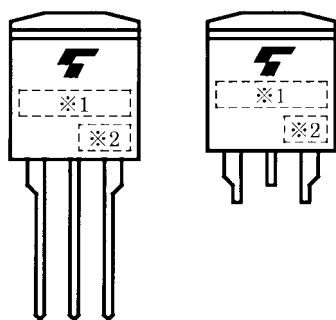
SF3G48,SF3J48,USF3G48,USF3J48**MEDIUM POWER CONTROL APPLICATIONS**

- Repetitive Peak Off-State Voltage : $V_{DRM} = 400,600V$
Repetitive Peak Reverse Voltage : $V_{RRM} = 400,600V$
- Average On-State Current : $I_T (AV) = 3A$
- Gate Trigger Current : $I_{GT} = 10mA \text{ MAX.}$

Unit: mm

SF3G48-SF3J48	USF3G48-USF3J48
<p>1. CATHODE 2. ANODE 3. GATE</p>	<p>1. CATHODE 2. ANODE (BACK SIDE) 3. GATE</p>
JEDEC —	JEDEC —
JEITA —	JEITA —
TOSHIBA 13-10J1B	TOSHIBA 13-10J2B

Weight: 1.7g

MARKING

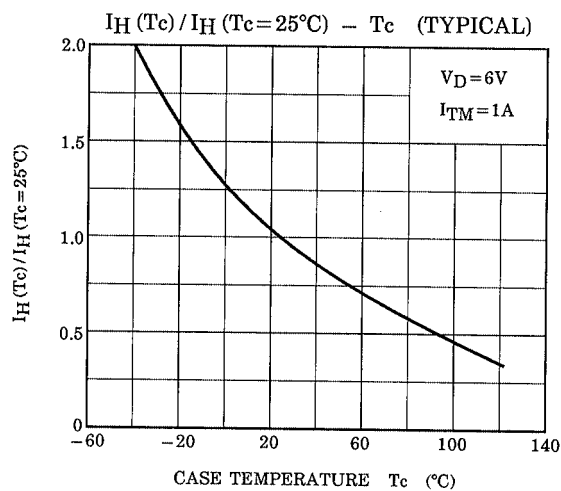
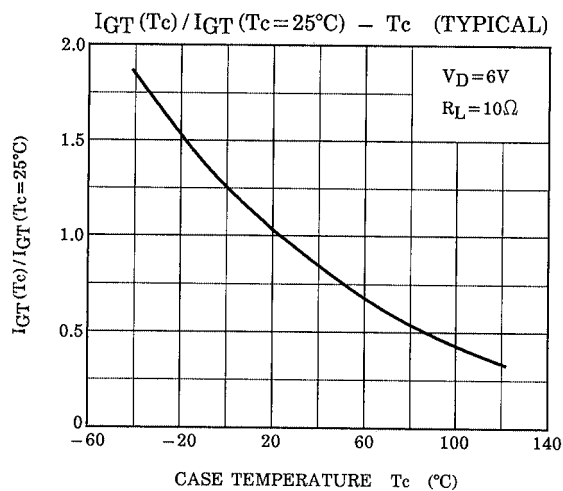
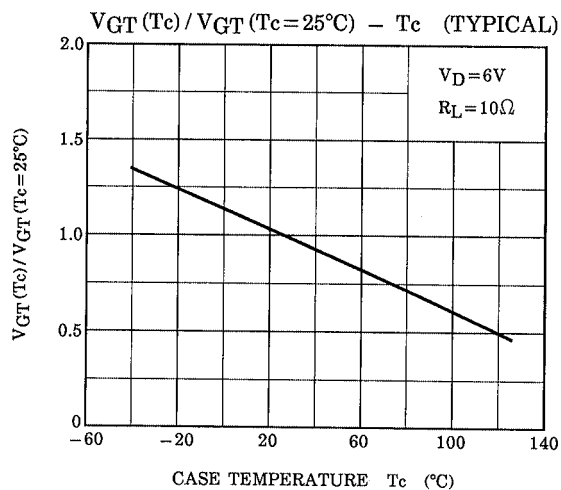
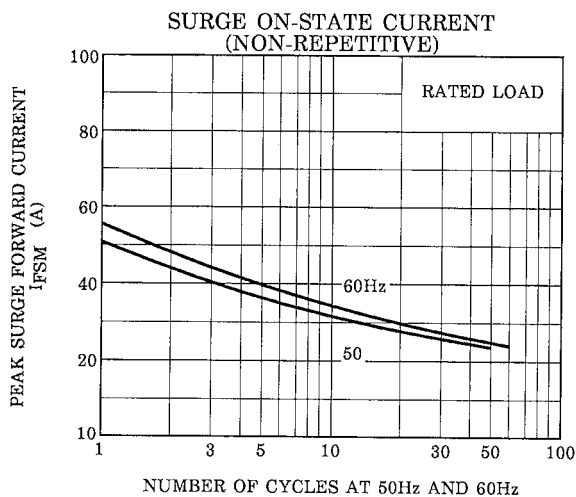
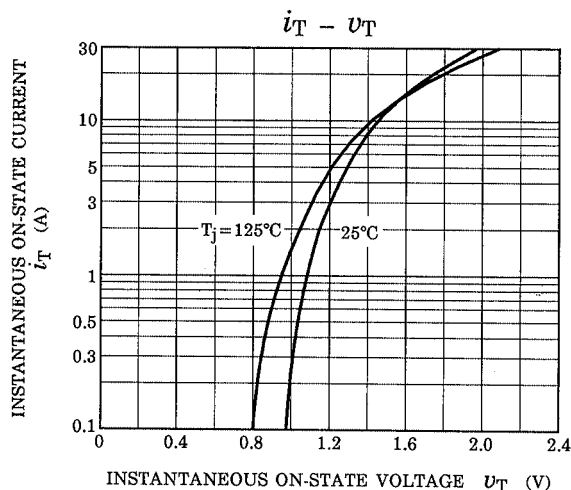
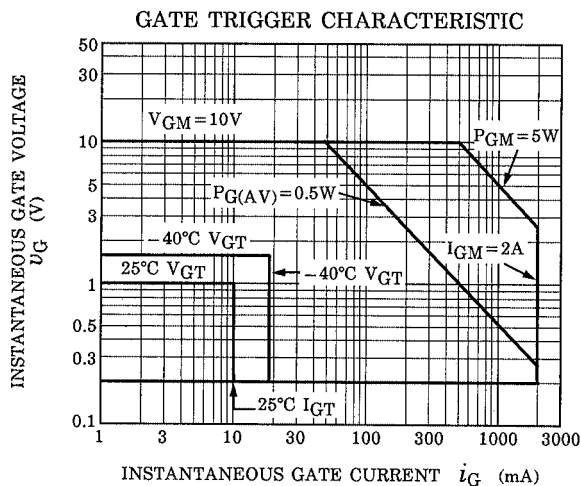
*1	MARK	F3G48	TYPE NAME	SF3G48, USF3G48
		F3J48		SF3J48, USF3J48
*2	Lot Number ← Month (Starting from Alphabet A) ← Year (Last Decimal Digit of the Current Year)			

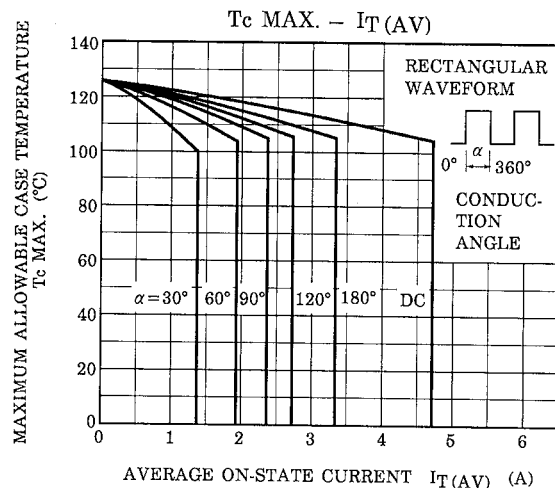
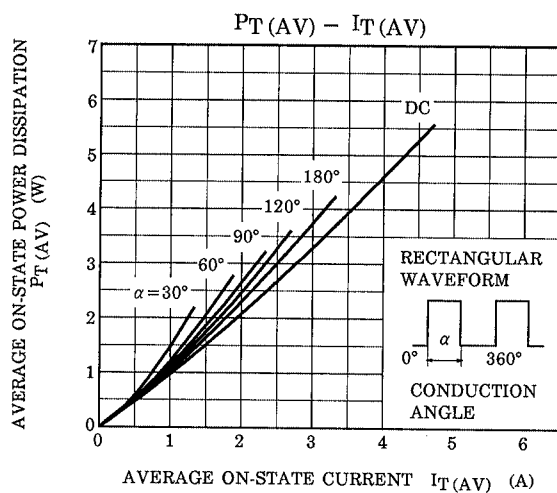
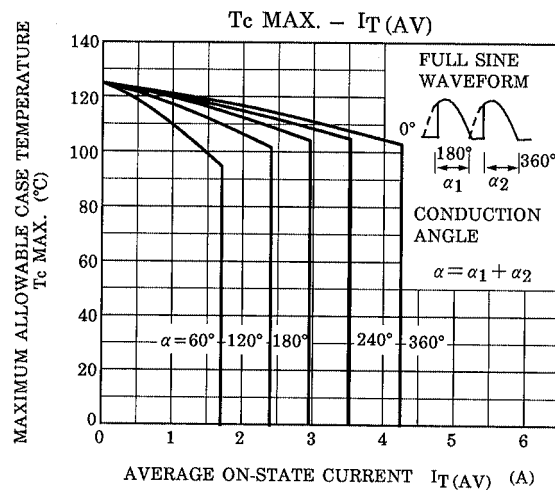
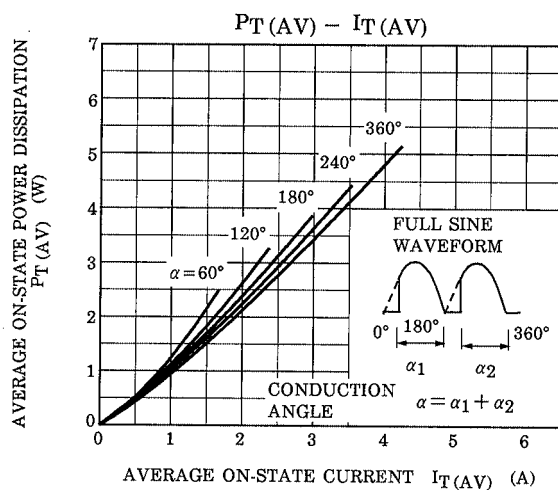
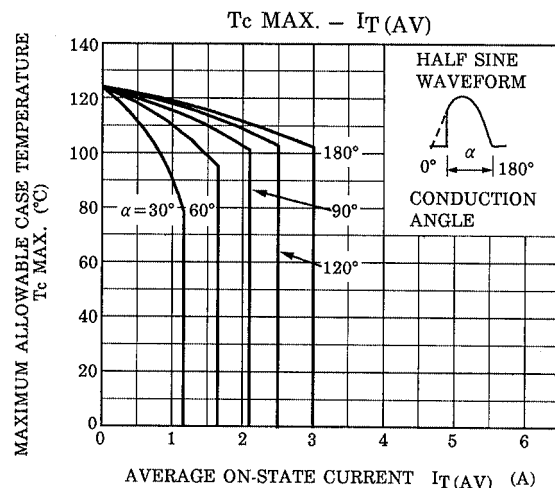
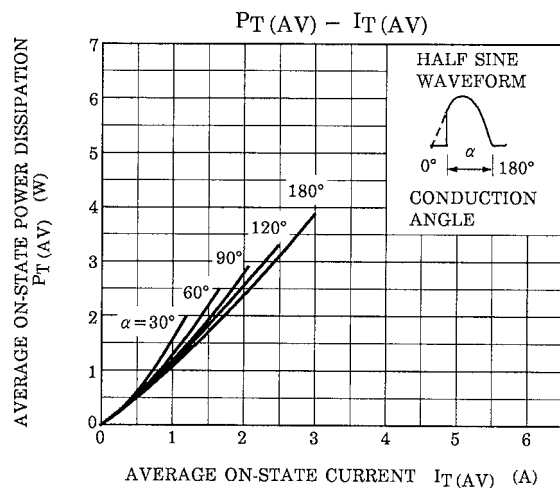
MAXIMUM RATINGS

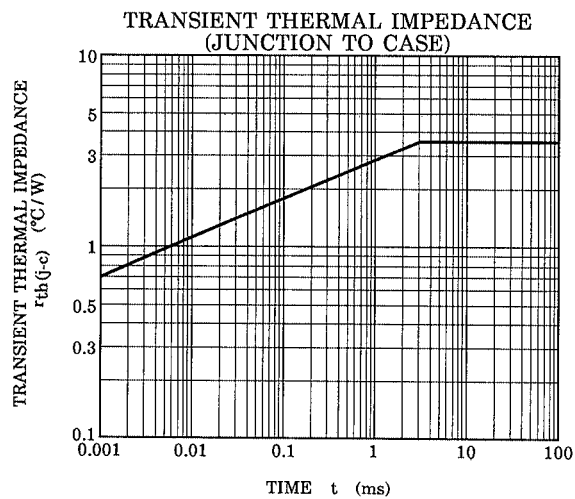
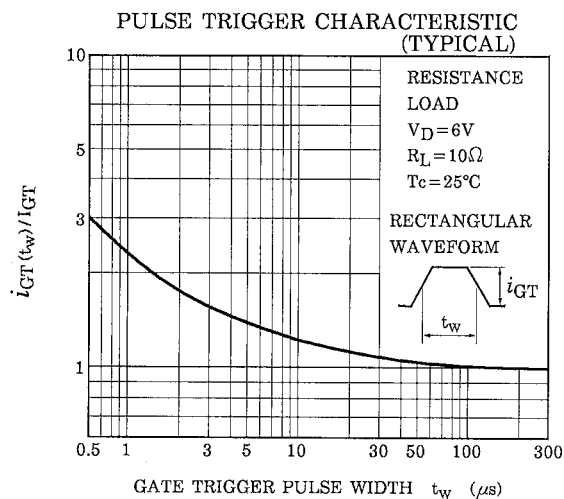
CHARACTERISTIC		SYMBOL	RATING	UNIT
Repetitive Peak Off-State Voltage and Repetitive Peak Reverse Voltage	SF3G48 USF3G48	V_{DRM} V_{RRM}	400	V
	SF3J48 USF3J48		600	
Non-Repetitive Peak Reverse Voltage (Non-Repetitive <5ms, $T_j = 0 \sim 125^\circ\text{C}$)	SF3G48 USF3G48	V_{RSM}	500	V
	SF3J48 USF3J48		720	
Average On-State Current		I_T (AV)	3	A
R.M.S On-State Current		I_T (RMS)	4.7	A
Peak One Cycle Surge On-State Current (Non-Repetitive)		I_{TSM}	50 (50Hz)	A
			55 (60Hz)	
I^2t Limit Value		I^2t	12.5	A^2s
Critical Rate of Rise of On-State Current (Note 1)		di / dt	100	$\text{A} / \mu\text{s}$
Peak Gate Power Dissipation		P_{GM}	5	W
Average Gate Power Dissipation		P_G (AV)	0.5	W
Peak Forward Gate Voltage		V_{FGM}	10	V
Peak Reverse Gate Voltage		V_{RGM}	-5	V
Peak Forward Gate Current		I_{GM}	2	A
Junction Temperature		T_j	-40~125	$^\circ\text{C}$
Storage Temperature Range		T_{stg}	-40~125	$^\circ\text{C}$

Note 1: $V_{DRM} = 0.5 \times \text{Rated}$ $I_{TM} \leq 12\text{A}$ $t_{gw} \geq 10\mu\text{s}$ $t_{gr} \leq 250\text{ns}$ $i_{gp} = I_{GT} \times 2.0$ **ELECTRICAL CHARACTERISTICS ($T_a = 25^\circ\text{C}$)**

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN	TYP.	MAX	UNIT
Repetitive Peak Off-State Current and Repetitive Peak Reverse Current	I_{DRM} I_{RRM}	$V_{DRM} = V_{RRM} = \text{Rated}$	—	—	10	μA
Peak On-State Voltage	V_{TM}	$I_{TM} = 12\text{A}$	—	—	1.5	V
Gate Trigger Voltage	V_{GT}	$V_D = 6\text{V}, R_L = 10\Omega$	—	—	1.0	V
Gate Trigger Current	I_{GT}		—	—	10	mA
Gate Non-Trigger Voltage	V_{GD}	$V_D = \text{Rated} \times 2 / 3, T_c = 125^\circ\text{C}$	0.2	—	—	V
Critical Rate of Rise of Off-State Voltage	dv / dt	$V_{DRM} = \text{Rated}, T_c = 125^\circ\text{C}$ Exponential Rise	—	50	—	$\text{V} / \mu\text{s}$
Holding Current	I_H	$V_D = 6\text{V}, I_{TM} = 1\text{A}$	—	—	40	mA
Latching Current	I_L	$V_D = 6\text{V}, f = 50\text{Hz}$ $t_{gw} = 50\mu\text{s}, i_G = 30\text{mA}$	—	—	50	mA
Thermal Resistance	$R_{th} (j-c)$	Junction to Case, DC	—	—	3.6	$^\circ\text{C} / \text{W}$







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